TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

# 2SD2481

Pulse Motor Drive, Hammer Drive Applications Switching Applications Power Amplifier Applications

- High DC current gain:  $h_{FE} = 4000$  (min) ( $V_{CE} = 2 \text{ V}$ , IC = 150 mA)
- Low saturation voltage: V<sub>CE</sub> (sat) = 1.5 V (max) (I<sub>C</sub> = 1 A, I<sub>B</sub> = 1 mA)

#### Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	$\langle \rangle$
Collector-base voltage	V <sub>CBO</sub>	30	V	
Collector-emitter voltage	V <sub>CEO</sub>	30	×	
Emitter-base voltage	V <sub>EBO</sub>	10	> v	
Collector current	Ι <sub>C</sub>	1.5	А	
Base current	Ι <sub>Β</sub>	0.15	A	
Collector power dissipation	P <sub>C</sub>	1.3	/w	
Junction temperature	Tj	150	3°	
Storage temperature range	T <sub>stg</sub>	-55 to 150	°C	$\geq$



Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the

Weight: 0.55 g (typ.)

reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



Electrical Characteristics (Ta = 25°C)

Chara	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off of	current	I <sub>CBO</sub>	V <sub>CB</sub> = 30 V, I <sub>E</sub> = 0	—	_	10	μA
Emitter cut-off cu	rrent	I <sub>EBO</sub>	V <sub>EB</sub> = 10 V, I <sub>C</sub> = 0	_	_	10	μA
Collector-emitter	breakdown voltage	V (BR) CEO	I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0	30	_		V
DC current gain		h <sub>FE</sub>	V <sub>CE</sub> = 2 V, I <sub>C</sub> = 150 mA	4000		_	
Collector-emitter	saturation voltage	V <sub>CE (sat)</sub>	I <sub>C</sub> = 1 A, I <sub>B</sub> = 1 mA	F	7(	1.5	V
Base-emitter satu	ration voltage	V <sub>BE (sat)</sub>	I <sub>C</sub> = 1 A, I <sub>B</sub> = 1 mA	77		2.2	V
Switching time	Turn-on time	t <sub>on</sub>	20 µs Input Output	$\underline{O}$	0.18	_	
	Storage time	t <sub>stg</sub>		_	0.6	/>	μs
	Fall time	t <sub>f</sub>	$V_{CC} \approx 15 \text{ V}$ $I_{B1} = -I_{B2} = 1 \text{ mA, duty cycle} \le 1\%$		0.3	) –	

### Marking



### **TOSHIBA**



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• The information contained herein is subject to change without notice.

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